

INFORMATION
DISCLOSURE
CITATION FORM FOR
PATENT APPLICATION
(FORM PTO - 1449)

Docket No.: 3536 C01

Serial No.: 09/775,173

Applicant(s): JAMES CARDUCCI, ET AL.

Filing Date: 01-31-01

Group: ~~1000~~ (763)RECEIVED
MAY 21 2001

TC 1700

U. S. PATENTS

Initials	Patent No	Issue Date	Name	Class	Subclass	Page
<i>gag</i>	5,401,351	03-28-95	SAMUKAWA			
	5,421,891	06-06-95	CAMPBELL ET AL.			
	5,429,070	07-04-95	CAMPBELL ET AL.			
	5,484,485	01-16-96	CHAPMAN			
	5,556,501	09-17-96	COLLINS ET AL.			
	5,662,819	09-02-97	KADOMURA			
	6,030,486	02-29-00	LOEWENHARDT, ET AL.			
<i>gag</i>	6,054,013	04-25-00	COLLINS, ET AL.			

FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Translation? (Yes/No/n/a)

Initials	Other Documents (Title, Author, Date, Pages, Etc., if known)
<i>gag</i>	U.S. Patent Application Serial No. 09/263,001, Filed March 5, 1999, entitled, "Magnetically Enhanced Inductively Coupled Plasma Reactor with Magnetically Confined Plasma," by Gerald Yin, et al.
	U.S. Patent Application Serial No. 09/521,799, Filed March 9, 2000, entitled, "Magnetically Enhanced Inductively Coupled Plasma Reactor with Magnetically Confined Plasma," by Gerald Yin, et al.
<i>gag</i>	U.S. Patent Application Serial No. 09/773, 409, Filed January 31, 2001, entitled, "Magnetically Enhanced Inductively Coupled Plasma Reactor with Magnetically Confined Plasma," by Peter Loewenhardt, et al.

Examiner's Signature:

George Goudreau

Date Considered:

9-031

Initial if reference was considered, whether or not citation with MPEP. Mark through citation if not considered. Include a copy of this citation form with your next correspondence to the Applicant(s).



INFORMATION DISCLOSURE CITATION FORM FOR PATENT APPLICATION (FORM PTO - 1449)	Docket No.: 3536 C01 Serial No.: 09/775,173
	Applicant(s): JAMES CARDUCCI, ET AL.
	Filing Date: 01-31-01 Group: 1763 1763

U. S. PATENTS

Initials	Patent No	Issue Date	Name	Class	Subclass	Filing Date

RECEIVED
MAY 17 2001
TC 1700

FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Translation? (Yes/No/NA)
GAG	HEI 8-264515	11.10.96	JAPAN	MITSUYOSHI IMAFUKU ET AL.	NA

Initials	Other Documents (Title, Author, Date, Pages, Etc., if known)
----------	--

Examiner's Signature: George Goudreau	Date Considered: 9-031
---------------------------------------	------------------------

Initial if reference was considered, whether or not citation with MPEP. Mark through citation if not considered. Include a copy of this citation form with your next correspondence to the Applicant(s).

INFORMATION
DISCLOSURE
CITATION FORM FOR
PATENT APPLICATION
(FORM PTO - 1449)

Docket No.: 3536 C01

Serial No.: 09/775,173

Applicant(s): JAMES CARDUCCI, ET AL.

Filing Date: 01-31-01

Group: ~~1763~~ 1763

U. S. PATENTS

Initials	Patent No	Issue Date	Name	Class	Subclass	Filing Date
<i>gag</i>	4,438,723 ✓	03-27-84	CANNELLA ET AL.			
	4,440,107 ✓	04-03-84	DOEHLER ET AL.			
	4,483,737 ✓	11-20-84	MANTEI			
	4,810,935 ✓	03-07-89	BOSWELL			
	4,842,707 ✓	06-27-89	KINOSHITA			
	4,990,229 ✓	02-05-91	CAMPBELL ET AL.			
	4,993,361 ✓	02-19-91	UNVALA			
	5,091,049 ✓	02-25-92	CAMPBELL ET AL.			
	5,122,251 ✓	06-16-92	CAMPBELL ET AL.			
	5,160,398 ✓	11-03-92	YANAGIDA			
	5,178,739 ✓	01-12-93	BARNES ET AL.			
	5,224,441 ✓	07-06-93	FELTS ET AL.			
<i>gag</i>	5,346,579 ✓	09-13-94	COOK ET AL.			

FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Transmitted
<i>gag</i>	EP 0 173 583 ✓	05.03.86	EUROPE	KIM KUYNGSHIK ET AL.	<i>NA</i>
	EP 0 651 425 ✓	03.05.95	EUROPE	ROBERT CHAPMAN	<i>NA</i>
	EP 0 786 794 ✓	03.07.97	EUROPE	PETER LOEWENHARDT ET AL.	<i>NA</i>
<i>gag</i>	7-22389 ✓	24.01.95	JAPAN	YUTAKA KAKCHI ET AL.	<i>NA</i>

Initials

Other Documents (Title, Author, Date, Pages, Etc., if known)

gag Quick, A.K., Chen, R.T.S., and Hershkovitz, N., "Etch rate and plasma density radial uniformity measurements in a cusped field helicon plasma etcher," *J. Vac. Sci. Technol.*, Vol. 14, No. 3, May/June 1996, pp. 1041-1045.

Examiner's Signature:

George Gaudreau

Date Considered:

9-03'

Initial if reference was considered, whether or not citation with MPEP. Mark through citation if not considered. Include a copy of this citation form with your next correspondence to the Applicant(s).

INFORMATION
DISCLOSURE
CITATION FORM FOR
PATENT APPLICATION
(FORM PTO - 1449)

Docket No.: 3536 C01

Serial No.: 09/775,173

Applicant(s): JAMES CARDUCCI, ET AL.

Filing Date: 01-31-01

Group: ~~1763~~ 1763

U. S. PATENTS

Initials	Patent No	Issue Date	Name	Class	Subclass	Filing Date
GAQ	6,074,518 ✓	06-13-00	IMAFUKU ET AL.	156	345	01-04-99
GAQ	6,189,484 ✓	02-20-01	YIN ET AL.	118	723	03-05-99

RECEIVED
JUN 11 2001
TECHNOLOGY CENTER 1700

FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Translation? (Yes/No/n/a)

Initials	Other Documents (Title, Author, Date, Pages, Etc., if known)
----------	--

Examiner's Signature:

George Goudreau

Date Considered:

9-031

Initial if reference was considered, whether or not citation with MPEP. Mark through citation if not considered. Include a copy of this citation form with your next correspondence to the Applicant(s).